

# STPS20M60S

## Power Schottky rectifier

## **Features**

- High current capability
- Avalanche rated
- Low forward voltage drop
- High frequency operation

### Description

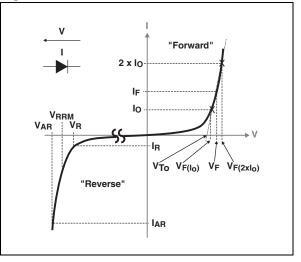
The STPS20M60S is a single Schottky diode, suited for high frequency switch mode power supply.

Packaged in TO-220AB, I<sup>2</sup>PAK and D<sup>2</sup>PAK, this device is intended to be used in notebook, game station and desktop adapters, providing in these aplications a good efficiency at both low and high load.

Table 1.   Device summary					
Symbol	Value				
I <sub>F(AV)</sub>	20 A				
V <sub>RRM</sub>	60 V				
V <sub>F</sub> (typ)	0.365 V				
T <sub>j</sub> (max)	150 °C				

# A٠ ٠K Δ I<sup>2</sup>PAK D<sup>2</sup>PAK STPS20M60SG-TR STPS20M60SR **TO-220AB** STPS20M60ST

Electrical characteristics<sup>(a)</sup> Figure 1.



 $V_{ARM}$  and  $I_{ARM}$  must respect the reverse safe a. operating area defined in *Figure 12*.  $V_{AR}$  and  $I_{AR}$  are pulse measurements (t<sub>p</sub> < 1  $\mu$ s). V<sub>R</sub>, I<sub>R</sub>, V<sub>RRM</sub> and V<sub>F</sub>, are static characteristics

October 2011

Doc ID 019045 Rev 1

### **Characteristics** 1

#### Absolute ratings (limiting values with terminals 1 and 3 short circuited at Table 2. T<sub>amb</sub> = 25 °C, unless otherwise specified)

Symbol		Value	Unit			
V <sub>RRM</sub>	Repetitive peak reverse ve	oltage			60	V
I <sub>F(RMS)</sub>	Forward rms current				90	А
I <sub>F(AV)</sub>	Average forward current, a	δ = 0.5	T <sub>c</sub> = 135 °C	Per package	20	А
I <sub>FSM</sub>	Surge non repetitive forwa	ard current	600	А		
P <sub>ARM</sub> <sup>(1)</sup>	Repetitive peak avalanche	e power	26400	W		
V <sub>ARM</sub> <sup>(2)</sup>	Maximum repetitive peak avalanche voltage	t <sub>p</sub> < 1 μs, T <sub>j</sub> <	80	V		
V <sub>ASM</sub> <sup>(2)</sup>	Maximum single-pulse peak avalanche voltage	t <sub>p</sub> < 1 μs, Τ <sub>j</sub> <	80	V		
T <sub>stg</sub>	Storage temperature rang	-65 to +175	°C			
Тj	Maximum operating juncti	on temperature	e <sup>(3)</sup>		150	°C

1. For temperature or pulse time duration deratings, please refer to Figure 4 and 5. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the application notes AN1768 and AN2025.

2. See Figure 12

 $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink 3.

#### Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
R <sub>th(j-c)</sub>	Junction to case	1.0	°C/W

#### Table 4. Static electrical characteristics (terminals 1 and 3 short circuited)

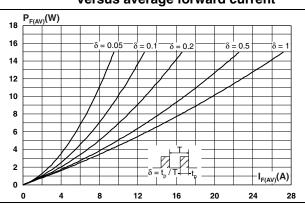
Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I <sub>B</sub> <sup>(1)</sup>	Reverse leakage	T <sub>j</sub> = 25 °C	VV	-	30	125	μΑ
'R'	current	$T_j = 125 \text{ °C}$ $V_R = V_{RRM}$	-	20	75	mA	
	$T_{j} = 25 \text{ °C}$ $T_{j} = 125 \text{ °C}$ $I_{F} = 10 \text{ A}$	T <sub>j</sub> = 25 °C	L = 10 A	-	0.465	0.500	
V <sub>F</sub> <sup>(2)</sup>		F = 10 A	-	0.365	0.405	v	
V <sub>F</sub> <sup>(2)</sup> Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 20 A	-	0.520	0.565	v	
		T <sub>j</sub> = 125 °C	F = 20  A	-	0.450	0.505	

1. Pulse test:  $t_p$  = 5 ms,  $\delta$  < 2 %

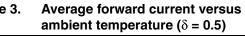
2. Pulse test:  $t_p$  = 380 µs,  $\delta$  < 2 %

To evaluate the conduction losses use the following equation: P = 0.380 x  $I_{F(AV)}$  + 0.0063 x  ${I_{F}}^{2}_{(RMS)}$ 





## Figure 2. Average forward power dissipation Figure 3. versus average forward current



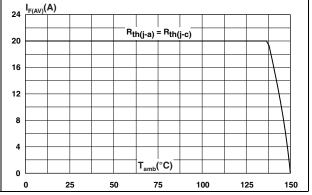


Figure 4. Normalized avalanche power derating versus pulse duration

Figure 5. Normalized avalanche power derating versus junction temperature

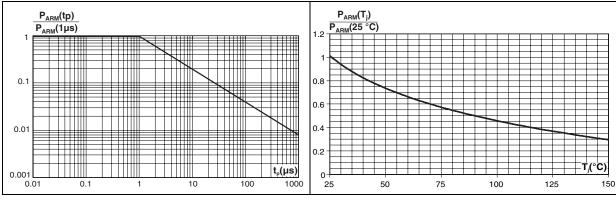
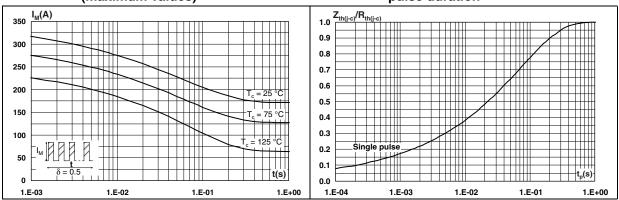


Figure 6. Non repetitive surge peak forward current versus overload duration (maximum values)

Figure 7. Relative variation of thermal impedance junction to case versus pulse duration





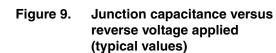
F = 1 MHz  $s_{c} = 30 \text{ mV}_{B}$ 

T<sub>i</sub> = 25 °C

 $V_{R}(V)$ 

100

### Figure 8. Reverse leakage current versus reverse voltage applied (typical values)



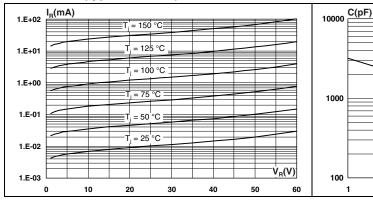
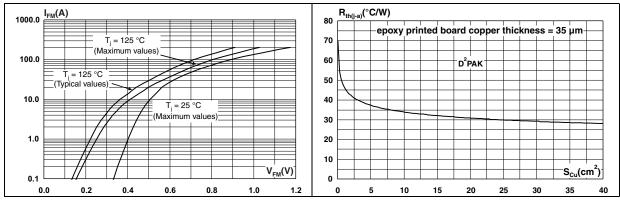


Figure 10. Forward voltage drop versus forward current

Figure 11. Thermal resistance junction to ambient versus copper surface under tab

10

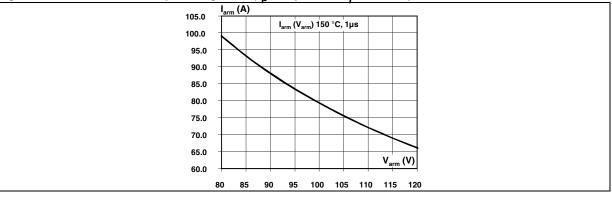


1000

100

1

Reverse safe operating area (t<sub>p</sub> < 1  $\mu$ s and T<sub>i</sub> < 150 °C) Figure 12.





## 2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK<sup>®</sup> is an ST trademark.

Table 5. TO-220AB dimensions

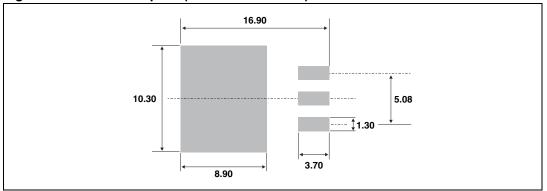
				Dimer	nsions							
								Ref.	Millin	neters	Inches	
			Min.	Max.	Min.	Max.						
		А	4.40	4.60	0.173	0.181						
		С	1.23	1.32	0.048	0.051						
H2 Dia	A	D	2.40	2.72	0.094	0.107						
		Е	0.49	0.70	0.019	0.027						
	L7	F	0.61	0.88	0.024	0.034						
L6		F1	1.14	1.70	0.044	0.066						
		F2	1.14	1.70	0.044	0.066						
F2		G	4.95	5.15	0.194	0.202						
	D ←→_	G1	2.40	2.70	0.094	0.106						
L4		H2	10	10.40	0.393	0.409						
F→ ←		L2	16.4	Тур.	0.645	5 Тур.						
G1,	M =	L4	13	14	0.511	0.551						
	K→ → E	L5	2.65	2.95	0.104	0.116						
G		L6	15.25	15.75	0.600	0.620						
		L7	6.20	6.60	0.244	0.259						
		L9	3.50	3.93	0.137	0.154						
		М	2.6	Тур.	0.102	2 Тур.						
		Dia.	3.75	3.85	0.147	0.151						



			Dimensions			
		Ref.	Millimeters		Inc	hes
·			Min.	Max.		
		А	4.40	4.60	0.173	0.181
	← A→	A1	2.49	2.69	0.098	0.106
	C2→←	A2	0.03	0.23	0.001	0.009
		В	0.70	0.93	0.027	0.037
L		B2	1.14	1.70	0.045	0.067
		С	0.45	0.60	0.017	0.024
↓ ↓ ↓ ↓ ↓ ▲		C2	1.23	1.36	0.048	0.054
		D	8.95	9.35	0.352	0.368
G		Е	10.00	10.40	0.393	0.409
	A2	G	4.88	5.28	0.192	0.208
		L	15.00	15.85	0.590	0.624
	M↓ ★↓ V2	L2	1.27	1.40	0.050	0.055
* =	LAT ZONE NO LESS THAN 2mm	L3	1.40	1.75	0.055	0.069
r.	LAT ZONE NO LESS I HAN ZIIIII	М	2.40	3.20	0.094	0.126
		R	0.40	typ.	0.016	6 typ.
		V2	0°	<b>8</b> °	<b>0</b> °	8°

Table 6.D<sup>2</sup>PAK dimensions

Figure 13. D<sup>2</sup>PAK footprint (dimensions in mm)





			Dimensions			
		Ref.	Millimeters		Inches	
			Min.	Max.	Min.	Max.
, É ,		Α	4.40	4.60	0.173	0.181
		A1	2.40	2.72	0.094	0.107
		b	0.61	0.88	0.024	0.035
	D	b1	1.14	1.70	0.044	0.067
		С	0.49	0.70	0.019	0.028
	A1	c2	1.23	1.32	0.048	0.052
		D	8.95	9.35	0.352	0.368
		е	2.40	2.70	0.094	0.106
		e1	4.95	5.15	0.195	0.203
e → +	→ C	E	10	10.40	0.394	0.409
l≪ e1→		L	13	14	0.512	0.551
		L1	3.50	3.93	0.138	0.155
		L2	1.27	1.40	0.050	0.055

Table 7.I<sup>2</sup>PAK dimensions



## **3** Ordering information

### Table 8.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS20M60ST	STPS20M60ST	TO-220AB	2.2 g	50	Tube
STPS20M60SR	STPS20M60SR	I <sup>2</sup> PAK	1.49 g	50	Tube
STPS20M60SG-TR	STPS20M60SG	D <sup>2</sup> PAK	1.48 g	1000	Tape and reel

## 4 Revision history

### Table 9.Revision history

Date	Revision	Changes
11-Oct-2011	1	Initial release



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